RoHS

HALOGEN

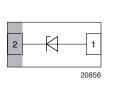
FREE

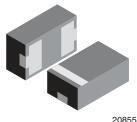
<u>GREEN</u>



# Vishay Semiconductors

## **ESD Protection Diode in LLP1006-2L**

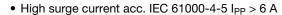




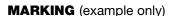
- Ultra compact LLP1006-2L package
- Low package height < 0.4 mm</li>
- 1-line ESD protection

**FEATURES** 

- Low leakage current < 0.01 μA
- Low load capacitance C<sub>D</sub> = 45 pF (V<sub>R</sub> = 0 V; f = 1 MHz)
- ESD immunity acc. IEC 61000-4-2
  ± 30 kV contact discharge
  ± 30 kV air discharge



- Soldering can be checked by standard vision inspection.
  No X-ray necessary
- Pin plating NiPdAu (e4) no whisker growth
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- PATENT(S): www.vishay.com/patents
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>



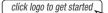


Bar = cathode marking

X = date code

Y = type code (see table below)







ORDERING INFORMATION					
DEVICE NAME ORDERING CODE		TAPED UNITS PER REEL (8 mm TAPE on 7" REEL)	MINIMUM ORDER QUANTITY		
VESD15A1-HD1	VESD15A1-HD1-G4-08	8000	8000		

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	YEIGHT   MOLDING COMPOUND   MOISTURE   SENSITIVITY LEVEL		SOLDERING CONDITIONS	
VESD15A1-HD1	LLP1006-2L	W	0.72 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C	

ABSOLUTE MAXIMUM RATINGS RATINGS VESD15A1-HD1						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	Acc. IEC 61000-4-5; $t_P = 8/20 \mu s$ ; single shot	I <sub>PPM</sub>	6	Α		
Peak pulse power	Acc. IEC 61000-4-5; $t_P = 8/20 \mu s$ ; single shot	P <sub>PP</sub>	150	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 30	kV		
Operating temperature	Junction temperature	$T_J$	-40 to +125	°C		
Storage temperature		T <sub>stg</sub>	-55 to +150	°C		

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and international patents.



## Vishay Semiconductors

ELECTRICAL CHARACTERISTICS VESD15A1-HD1 (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of line which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	15	V		
Reverse voltage	At I <sub>R</sub> = 0.1 μA	$V_R$	15	-	-	V		
Reverse current	At V <sub>R</sub> = 15 V	I <sub>R</sub>	-	< 0.01	0.1	μA		
Reverse breakdown voltage	At I <sub>R</sub> = 1 mA	$V_{BR}$	15.5	16	17	V		
Reverse clamping voltage	At I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	18	20	V		
	At I <sub>PP</sub> = I <sub>PPM</sub> = 6 A	V <sub>C</sub>	-	24	27	V		
Forward clamping voltage	At I <sub>PP</sub> = 0.2 A	$V_{F}$	-	0.85	1.2	V		
	At I <sub>PP</sub> = 1 A	$V_{F}$	-	1.1	1.3	V		
	At I <sub>PP</sub> = I <sub>PPM</sub> = 6 A	$V_{F}$	-	2.0	2.5	V		
Capacitance	At $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>	-	45	50	pF		
	At V <sub>R</sub> = 7.5 V; f = 1 MHz	C <sub>D</sub>	-	18	-	pF		
Clamping voltage	Transmission line pulse (TLP), $t_p = 100 \text{ ns}$ $I_{TLP} = 8 \text{ A}$	V <sub>C-TLP</sub>	-	19	-	V		
	Transmission line pulse (TLP), $t_p = 100 \text{ ns}$ $I_{TLP} = 16 \text{ A}$	V <sub>C-TLP</sub>	-	20.5	-	V		
Dynamic resistance	Transmission line pulse (TLP), t <sub>p</sub> = 100 ns	R <sub>DYN</sub>	-	0.27	-	Ω		

#### **BiAs-MODE** (bidirectional asymmetrical protection mode)

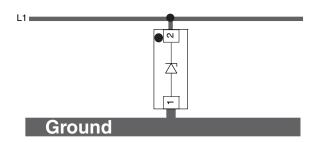
(resistance and inductance) of the protection device.

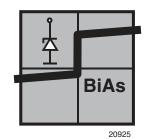
With the VESD15A1-HD1 one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V<sub>RWM</sub>) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch. As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V<sub>F</sub>) clamps the negative transient close to the ground level.

clamping voltage (V<sub>C</sub>) is defined by the breakthrough voltage (V<sub>BR</sub>) level plus the voltage drop at the series impedance

Due to the different clamping levels in forward and reverse direction the VESD15A1-HD1 clamping behavior is bidirectional and asymmetrical (BiAs).





# Vishay Semiconductors

## **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

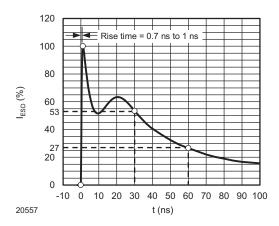


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega$ /150 pF)

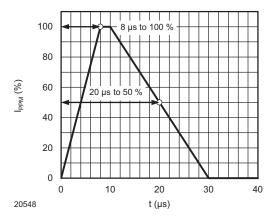


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

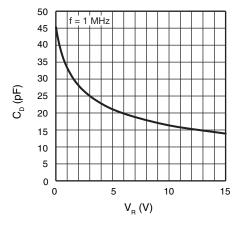


Fig. 3 - Typical Capacitance  $C_D$  vs. Reverse Voltage  $V_R$ 

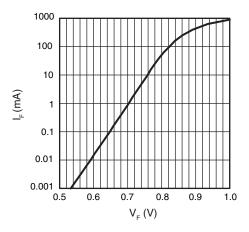


Fig. 4 - Typical Forward Current  $I_{\text{F}}$  vs. Forward Voltage  $V_{\text{F}}$ 

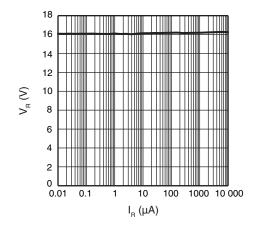


Fig. 5 - Typical Reverse Voltage  $V_R$  vs. Reverse Current  $I_R$ 

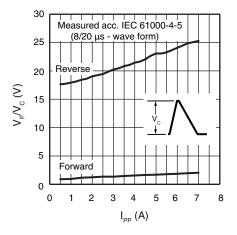


Fig. 6 - Typical Clamping Voltage vs. Peak Pulse Current I<sub>PP</sub>

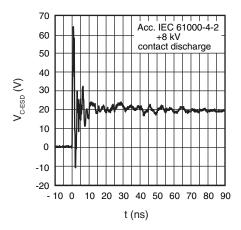


Fig. 7 - Typical Clamping Performance at +8 kV Contact Discharge (acc. IEC 61000-4-2)

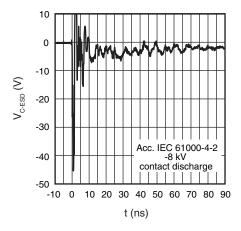


Fig. 8 - Typical Clamping Performance at -8 kV Contact Discharge (acc. IEC 61000-4-2)

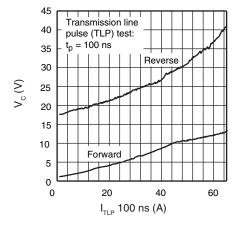
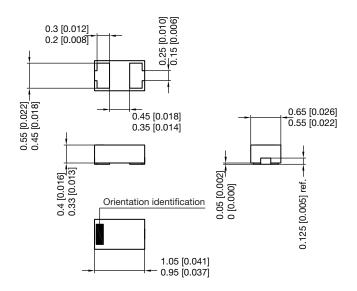


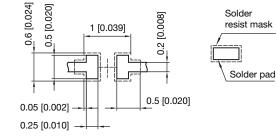
Fig. 9 - Typical Peak Clamping Voltage vs. TLP current (TLP = transmission line pulse;  $t_p = 100 \text{ ns}$ )

# Vishay Semiconductors

## PACKAGE DIMENSIONS in millimeters (inches): LLP1006-2L



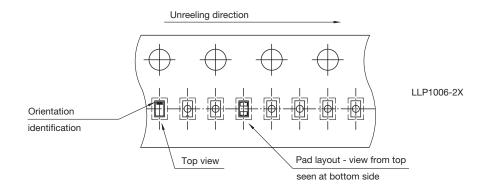
#### Foot print recommendation:



Pad Design Patented: (PUS 9.018.537 B2)

Document no.: S8-V-3906.04-005 (4) Rev. 7 - Date: 11.May 2016

20812



S8-V-3906.04-017 (4) 02.05.2017



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